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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Inventor(s):

Jae-Kyu LEE

Serial No.:

10/626,248

Examiner:

Not yet assigned

Filing Date:

July 23, 2003

Group Art Unit: 2812

Title:

METHOD FOR FORMING SHALLOW WELL OF SEMICONDUCTOR DEVICE USING

LOW-ENERGY ION IMPLANTATION

Confirmation No.

1012

Confirmation No. 1012	
Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450	
INFORMATION D	DISCLOSURE STATEMENT
or before mailing date of first office act under 37 CFR 1.97 (c) together wi Statement under 37 CFR a \$180 fee under 37 CFR (After mailing of first Office Action under 37 CFR 1.97 (d) together wi Statement under 37 CFR a \$180.00 fee set forth in (Filed after final action or notice the issue fee) Applicant(s) submit herewith For copies of patents, publications or other information	tional application; or date of entry of International application; tion on the merits; whichever occurs last) ith either a: 1.97 (e), or 1.17 (p); or on, but prior to Notice of Allowance or Final Office Action) ith: 1.97 (e), and
with 37 CFR 1.56.	
it is requested that the information disclosed	d herein be made of record in this application.
Any deficiency or overpayment should be duplicate copy of this sheet is enclosed.	charged or credited to deposit account number 13-1703. A
Customer No. 20575	Respectfully submitted, MARGER JOHNSON & McCOLLOM, P.C. Hosoon Lee Limited Recognition Under 37 CFR § 10.9(b)
MARGER JOHNSON & McCOLLOM, P.C. 1030 SW Morrison Street Portland, OR 97205 503-222-3613	I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Mail Stop Amendment Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 Date: September 13, 2004

Li Mei Vermilya

PATENT APPLICATION

Atty. Docket No.: Applicant: Filing Date:

9898-277

Serial No.

10/626,248

Jae-Kyu LEE July 23, 2003

Group:

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INFORMATION DISCLOSURE CITATION FORM PTO-1449 (Modified)

U.S. PATENT DOCUMENTS

Exam <u>Init</u>	Ref	Document <u>Number</u>	Issue <u>Date</u>	<u>Name</u>	Class	Sub <u>Class</u>		
FOREIGN PATENT DOCUMENTS								
Exam <u>Init</u>	Ref	Document Number	Publication Date	Country	<u>Name</u>			
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OTHER DOCUMENTS								
Exam Init Ref Author, Title, Date, Pertinent Pages, Etc.) English language abstract of Japanese Patent No. 11-340461								
	English language abstract of Korean Publication No. 2001-0064965							
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Examine	r:							
Date Con	sidered:							